

STRUCTURE Silicon Monolithic Integrated Circuit

PRODUCT SERIES 8-Channel Switching Regulator Controller for Digital Camera

**BD9757MWV TYPE** 

PIN ASSIGNMENT Fig.1 **BLOCK DIAGRAM** Fig.2 **PACKAGE** Fig.3

**Functions** ●1.5V minimum input operating

- Supplies power for the internal circuit by step-up converter(CH1).
- Contains step-up converter(2ch), step-down converter(4ch), inverting (1ch), with 31 step brightness controller for step-up converter(1ch).
- •5channels contain transistor for synchronous rectifying action mode.
- ●2channels contain FETs for the step-up converter.
- All channels contain internal compensation.
- It is possible separately control except CH1 and CH3.
- Operating frequency 1.2MHz(CH1~5), 600kHz(CH6~8).
- Contains output interception circuit when over load.
- •2 channels have high side switches with soft start function.
- ●Thermally enhanced UQFN044V6060 package(6mm x 6mm, 0.4mm pitch).

#### OAbsolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limit	Unit
Power Supply Voltage	VBAT	<b>−0.3~</b> 7	V
	VHx1~5	<b>−0.3~7</b>	٧
Power Input Voltage	HS78H	−0.3~7	V
	VLx7,8	−0.3~22	V
	IomaxLx1	±2.5	Α
Output Current	IomaxHx1	±1.5	Α
	IomaxHx2,5	+1.0	Α
	IomaxHx3,4	+0.8	Α
	IomaxHS78	+12	Α
	IomaxLx7,8	±1.0	Α
Power Dissipation	Pd	0.54 (*1)	W
Operating Temperature	Topr	<b>−25~+85</b>	°C
Storage Temperature	Tstg	<b>−55~+150</b>	°C
Junction Tempareture	Tjmax	+150	°C

<sup>(\*1)</sup> Without external heat sink, the power dissipation reduces by 432mW/°C over 25°C

### ORecommended operating conditions

OCH8 recommended operating conditions

Parameter	Symbol		Unit			
Parameter	Symbol	MIN	TYP	MAX	Unit	
Power Supply Voltage	VBAT	1.5	-	5.5	٧	
VREF Pin Connecting Capacitor	CVREF	0.47	1.0	4.7	μF	
VREGA Pin Connecting Capacitor	CVREGA	0.47	1.0	4.7	μF	

Status of

The Japanese version of this document is the official specification. Please use the translation version of this document as a reference to expedite understanding of the official version.

If these are any uncertainty in translation version of this document, official version takes priority.

Parameter	Symbo	MIN	TYP	MAX	Unit
Fixed H when determine brightness	T(ON)	265X1/fosc	-	-	S
Fixed L when OFF	T(OFF)	256X1/fosc	ı	-	S
Fixed H when setting brightness	T(H)	500	1	10000	nS
Fixed L when setting brightness	T(L)	500	ı	10000	nS
Fixed H when EN start-up	T(EN)	4X1/fosc	ı	-	S
Fixed L before setting brightness	T(CLR)	7X1/fosc	ı	255X1/fosc	S
Brightness setting time When start-up	T(SET)	_	-	2048X1/fosc	S



OElectrical characteristics (Ta=25°C, VCCOUT=5.0V, VBAT=3V, STB13~7=3V,UPIC8=2.5V)

						<u> </u>
Parameter	Symbol	MIN	Limit	MAX	Unit	Conditions
[Internal Regulat	tor VREGA]	1744		11000	l	
Output		24	25	20	V	IEA
Voltage	VREGA	2.4	2.5	2.6	V	Io=5mA
[Prevention Circ	cuit of Miss Op	eration by L	.ow voltage	input]		ı
Threshold Voltage	Vstd1	-	2.0	23	V	VREGA Monitor
Hysteresis	44.4		400		.,	
Width1	\_\Vstd1	50	100	200	mV	
Threshold Voltage 2	Vstd2	-	2.4	2.5	V	VCCOUT Monitor
Hysteresis						
Width	_\_Vstd1	100	200	300	mV	
(Short Circuit P	rotection]					
SCP detect time	Tscp	20	25	30	ms	
Timer start						
threshold	Vtcinv	0.38	0.48	0.58	V	INV Monitor CH3~5
voltage	.1					
Start-up Circui	t.) Fstart	150	300	600	kHz	
Start-up	1 Sual L	100	300	500	IN IZ	
VBAT	Vst1	1.5	-	-	V	
Voltage						
Start-up CH Soft Start	Tss1	1.8	3.0	5.3	msec	
Time						
[Oscillator]						
Frequency	fosc1	1.0	12	1.4	MHz	
CH1~5 Frequency						
CH6~8	fosc2	0.5	0.6	0.7	MHz	
Max duty						
2,3,4,5 (step-down)	Dmax1d	_	_	100	%	(※1)
Max duty 1						
(step-up)	Dmax1u	86	92	96	%	
Max duty	Dmax2	86	92	96	%	
6,7,8		<u> </u>	<u> </u>	<u> </u>	<u> </u>	
[Error Amp] Input Bias		1	1	1	1	
current	INV	-	0	50	nΑ	INV1~8, NON6=3.0V
INV threshold	VINV1	0.79	0.80	0.81	٧	CH1~5
1		0.70	0.00	0.01	-	5.11
INV threshold 2	VINV2	0.99	1.00	1.01	٧	CH7,8V
INV threshold	VINV3	370	400	430	mV	CH8I
3 (max)			100	-100		SI IO
	[For Inverting Base Bias Voltage Vref]					
CH6 Output Voltage	VOUT6	-6.09	-6.00	-5.91	٧	NON5 12kΩ, 72kΩ (※2)
Line	DVLi		4.0	12.5	mV	VCCOUT=28~5.5V
Regulation	חאח		4.0	12.0	111V	VUUU1-20~00V
Output Current When	los	02	1.0	_	mA	Vref=0V
Shorted				<u> </u>		
[Soft Start]						
CH2,5 Soft	Tss2,5	3.4	4.4	5.4	msec	
Start Time CH3,4 Soft						
Start Time	Tss3,4	12	22	32	msec	
CH6 Soft	Tss6	3.4	4.4	5.4	msec	
Start Time		J.,		J.,	500	
CH7,8 Soft Start Time	Tss7,8	4.4	5.4	6.6	msec	

_		Limit			Unit			
Parameter		Symbol	MIN	TYP			Conditions	
[Output Driver]								
CH1 Highside SW ON Resistance		RON1p	-	120	270	mΩ	Hx1=5V	
CH1 Lowside Resistance		RON1N	-	80	240	mΩ	VCCOUT=50V	
CH2 Highside Resistance		RON21p	-	250	400	mΩ	Hx2=3V	
CH2 Lowside Resistance	SWON	RON21N	-	250	400	mΩ	VCCOUT=50V	
CH3 Highside Resistance		RON3p	-	250	400	mΩ	Hx3=3V , VCCOUT=5V	
CH3 Lowside Resistance		RON3N	-	250	400	mΩ	VCCOUT=50V	
CH4 Highside Resistance	SWON	RON4p	-	250	400	mΩ	Hx4=3V, VCCOUT=5V	
CH4 Lowside Resistance	SWON	RON4N	-	250	400	mΩ	VCCOUT=50V	
CH5 Highside Resistance		RON5p	-	250	400	mΩ	Hx5=3V	
CH5 Lowside Resistance	SWON	RON5N	-	150	300	mΩ	VCCOUT=50V	
CH6 Driver O voltage H	utput	Vout6H	VCCOUT -1.5	VCCOUT -1.0	-	٧	IOUT6=50mA ,NON6=0.2V	
CH6 Driver O voltage L	utput	Vout6L	-	0.5	1.0	٧	IOUT6=-50mA NON6=-0.2V	
CH7,8 NMOS Resistance	SWON	RON7,8 N	-	500	800	mΩ	VCCOUT=50V	
CH7,8 Load S Resistance	W ON	RON7,8p	-	200	350	mΩ	HS7,8H=3V, VCCOUT=5,0V	
[STB13~7]		•	•	•	•			
STB	Active	VSTBH 1	1.5	-	5.5	٧		
Control voltage	Not Active	VSTBL1	-0.3	-	0.3	٧		
Pull down Res	Pull down Resistance		250	400	700	kΩ		
[UPIC8]								
UPIC8	Active	VUPIH	21	-	4.00	٧		
Control voltage	Not Active	VUPIL	0	-	0.40	٧		
Pull down Res		RUPIC1	30	50	80	kΩ		
[Circuit Curre	ent]	1	1	l			1	
	VBAT terminal	ISTB1	-	-	5	μΑ		
Stand-by	Hx terminal	ISTB2	-	-	5	μΑ	Step down	
Current	Lx terminal	ISTB3	-	-	5	μА	Step up	
	HS7,8H terminal	ISTB4	-	-	5	μΑ		
Circuit Current when start-up (VBAT current when voltage supplied for the terminal)		IST	-	150	450	μΑ	VBAT=1.5V	
Circuit Current 1 (VBAT current when voltage supplied for the terminal)		Icc1	-	45	150	μА	VBAT=3.0V	
Circuit Current 2 (VCCOUT current when voltage supplied for the terminal)		lcc2	-	5.0	9.7	mA	INV1~8=1.2V , NON6=-0.2V	

<sup>(%1)</sup>The protective circuit start working when circuit is operated by 100% duty.

So it is possible to use only for transition time shorter than charge time for SCP.

<sup>(</sup>%2)Recommend resistor value over 20k $\Omega$  between VREF to NON6, because VREF current is under 100uA.

<sup>©</sup>This product is not designed for normal operation with in a radioactive environment



### **OBlock Diagram**

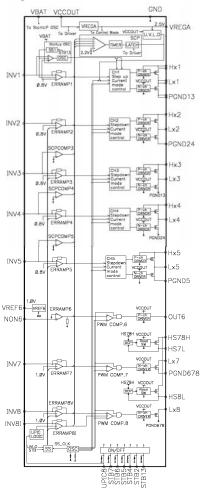
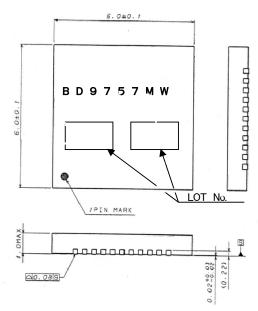


Fig.1

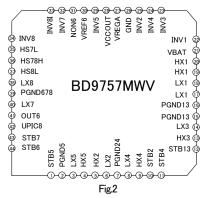
### **OPackage**



## **OPin Description**

端子名	機能				
VBAT	Input for battery voltage				
VCCOUT	Power Supply Input Terminal voltage				
100001	(Input CH1 output voltage)				
GND	Ground terminal				
PGND13, 24, 5, 678	Ground terminal for internal FET				
VREGA	VREGA Output				
VREF6	CH6 base bias voltage				
OUT6	Terminal for connecting gate of CH6 PMOS				
Hx1,2,3,4,5	Input terminal for synchronous High side switch, Power supply for Pch Driver				
Lx1,23,45,7,8	Terminal for connecting inductors				
HS78H	Power supply for internal load switch				
HS7L,HS8L	Output terminal for internal load switch				
INV1,2,3,4,5,7,8	Error AMP inverted input				
NON6	Error AMP non-inverted input				
INV8I	Error AMP inverted input				
STB13,2,4,5,6,7	ON/OFF switch				
	H: operating over 1.5V				
UPIC8	CH8 ON/OFF switch,				
UPIGO	for CH8 brightness control				

## **OPin Assignment**



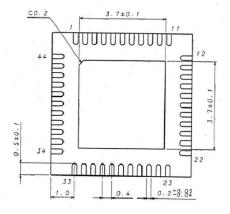


Fig.3



#### OOperation Notes

#### 1.) Absolute maximum ratings

This product is produced with strict quality control. However, the IC may be destroyed if operated beyond its absolute maximum ratings. If the device is destroyed by exceeding the recommended maximum ratings, the failure mode will be difficult to determine. (E.g. short mode, open mode) Therefore, physical protection counter-measures (like fuse) should be implemented when operating conditions beyond the absolute maximum ratings anticipated.

### 2.) GND potential

Make sure GND is connected at lowest potential. All pins except NON6, must not have voltage below GND. Also, NON6 pin must not have voltage below - 0.3V on start up.

#### 3.) Setting of heat

Make sure that power dissipation does not exceed maximum ratings.

#### 4.) Pin short and mistake fitting

Avoid placing the IC near hot part of the PCB. This may cause damage to IC. Also make sure that the output-to-output and output to GND condition will not happen because this may damage the IC.

#### 5.) Actions in strong magnetic field

Exposing the IC within a strong magnetic field area may cause malfunction.

#### 6.) Mutual impedance

Use short and wide wiring tracks for the main supply and ground to keep the mutual impedance as small as possible. Use inductor and capacitor network to keep the ripple voltage minimum.

#### 7.) Voltage of STB pin

The threshold voltages of STB pin are 0.3V and 1.5V. STB state is set below 0.3V while action state is set beyond 1.5V. The region between 0.3V and 1.5V is not recommended and may cause improper operation.

The rise and fall time must be under 10msec. In case to put capacitor to STB pin, it is recommended to use under 0.01 µF.

#### 8.) Thermal shutdown circuit (TSD circuit)

The IC incorporates a built-in thermal shutdown circuit (TSD circuit). The thermal shutdown circuit (TSD circuit) is designed only to shut the IC off to prevent runaway thermal operation. It is not designed to protect the IC or guarantee its operation. Do not continue to use the IC after operating this circuit or use the IC in an environment where the operation of this circuit is assumed.

#### 9.) Rush current at the time of power supply injection.

An IC which has plural power supplies, or CMOS IC could have momentary rush current at the time of power supply injection. Please take care about power supply coupling capacity and width of power Supply and GND pattern wiring.

### 1 O.)IC Terminal Input

This IC is a monolithic IC that has a P- board and P+ isolation for the purpose of keeping distance between elements. A P-N junction is formed between the P-layer and the N-layer of each element, and various types of parasitic elements are then formed. For example, an application where a resistor and a transistor are connected to a terminal (shown in Fig.9):

- OWhen GND > (terminal A) at the resistor and GND > (terminal B) at the transistor (NPN), the P-N junction operates as a parasitic diode.
- OWhen GND > (terminal B) at the transistor (NPN), a parasitic NPN transistor operates as a result of the NHayers of other elements in the proximity of the aforementioned parasitic diode.

Parasitic elements are structurally inevitable in the IC due to electric potential relationships. The operation of parasitic elements Induces the interference of circuit operations, causing malfunctions and possibly the destruction of the IC. Please be careful not to use the IC in a way that would cause parasitic elements to operate. For example, by applying a voltage that is lower than the GND (P-board) to the input terminal.

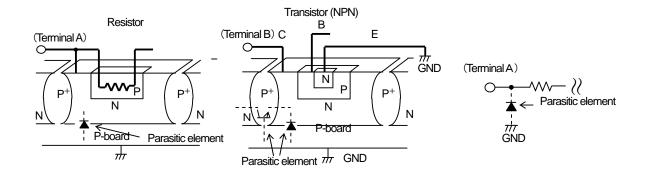


Fig - 9 Simplified structure of a Bipolar IC

#### Notes

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